

Supplementary Information

Mesoporous Niobium-Doped Titanium Dioxide Films from the Assembly of Crystalline Nanoparticles:
on the Relationship between Band Structure, Conductivity and Charge Storage Mechanism

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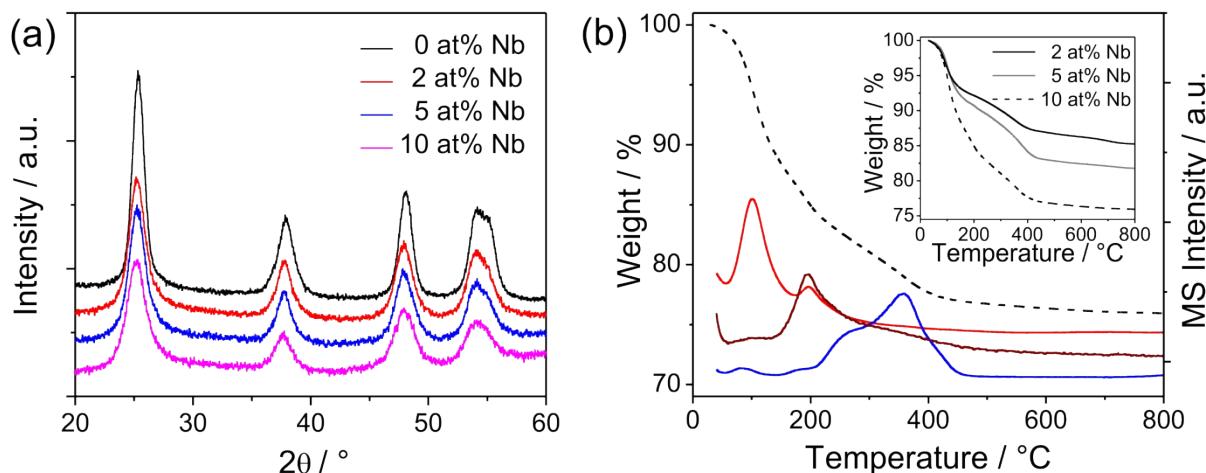


Figure S1. (a) XRD patterns of as-prepared TiO₂ and Nb-doped TiO₂ nanoparticles. The determined crystallite sizes are 4.7 nm (pure TiO₂), 4.9 nm (2 at% Nb), 4.9 nm (5 at% Nb) and 4.2 nm (10 at% Nb), respectively. (b) Combined thermogravimetric analysis/mass spectrometry (TGA–MS) data of as-prepared Nb-doped TiO₂ nanoparticles in synthetic air at 5 °C/min. A total mass loss of approx. 15%, 18% and 24% by 800 °C (inset) was observed for samples with 2 at% Nb, 5 at% Nb and 10 at% Nb, respectively. The MS analysis shows H₂O ($m/e = 18$, $I \times 0.5$) in red, HCl ($m/e = 36$, $I \times 10$) in brown and CO₂ ($m/e = 44$, $I \times 5$) in blue. As can be seen, adsorbed water molecules and solvent residues desorb in the temperature range between 60 and 200 °C, while the combustion of covalently bonded organic ligands (e.g., C₆H₁₃O) and the release of hydrochloric acid gas by thermal cleavage of Ti–Cl bonds were found to occur between 200 °C and 400 °C.

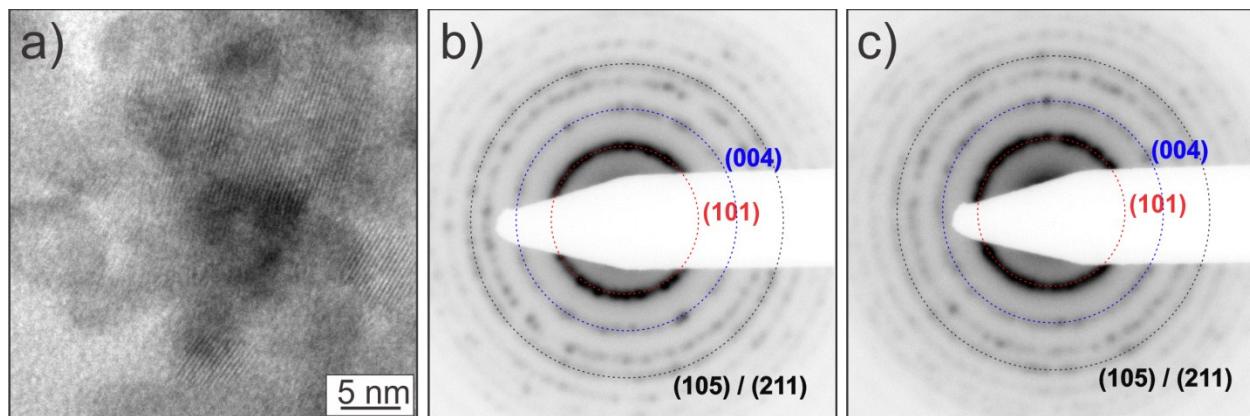


Figure S2. (a) Representative HRTEM image of as-prepared (2 at%) Nb-doped TiO₂ nanoparticle. (b, c) SAED patterns of doped TiO₂ nanoparticle for 2 at% Nb and 5 at% Nb.

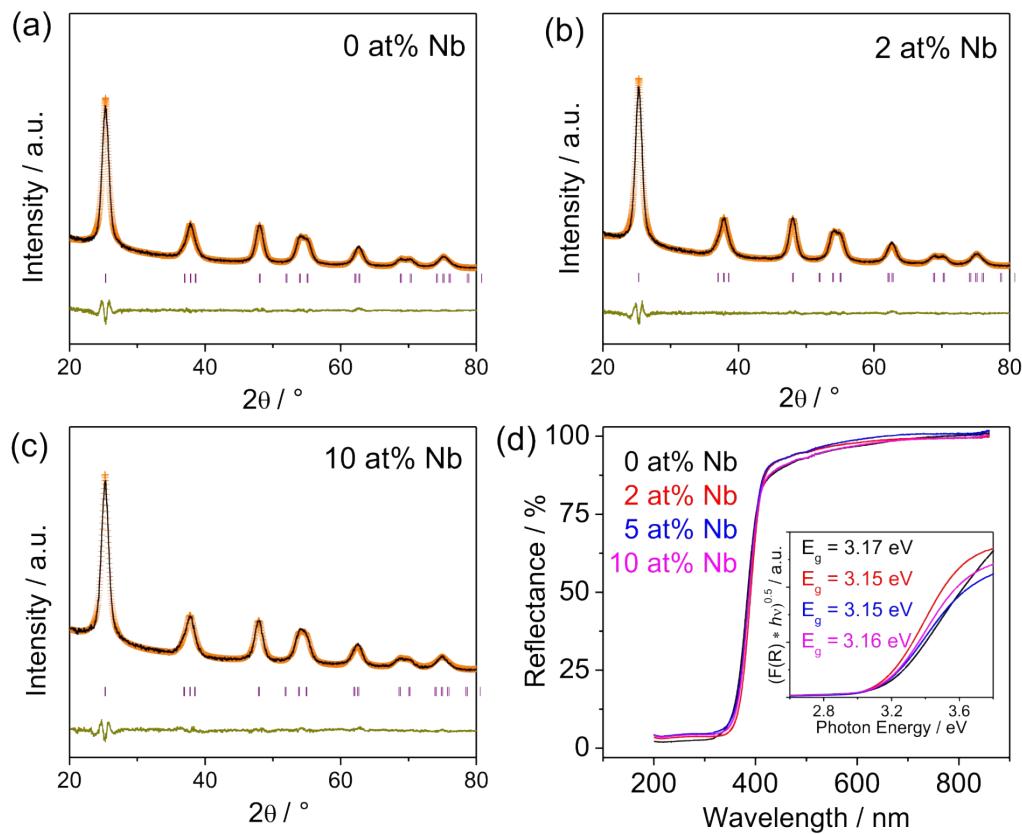


Figure S3. Rietveld refined XRD patterns of TiO₂ nanoparticles with different Nb doping level: (a) pure TiO₂; (b) 2 at% Nb and (c) 10 at% Nb. (d) UV-visible reflectance spectra of Nb-doped TiO₂ materials after heat treatment at 400 °C for 1 hour. The Tauc plot shown in the inset indicates indirect optical band gaps (E_g) at 3.17, 3.15, 3.15 and 3.16 eV (error margin ± 0.05 eV), respectively.

Table S1. Summary of refined structural parameters of doped TiO₂ nanoparticles after thermal treatment for 1 h at 400 °C. For purposes of comparison reference data are also given in Table S2.

Composition	TiO ₂	2 at% Nb	5 at% Nb	10 at% Nb
Space group	<i>I</i> 4 ₁ /amd (#141)			
Lattice parameters / Å	<i>a</i> , <i>b</i>	3.787	3.789	3.792
	<i>c</i>	9.508	9.511	9.520
Unit cell volume / Å ³	136.59	136.62	136.94	137.53
Calc. density / g cm ⁻³	4.159	4.156	4.128	4.311
Average grain size / nm	6.4	6.2	6.5	5.5
Average maximum microstrain / ×10 ⁻⁴	62	60	60	64
<i>R</i> _{wp} [Bragg contributions] / %	9.17	8.37	9.30	12.4
Goodness of fit, χ^2	1.75	1.55	2.08	3.21

Table S2. Structural parameters of nanocrystalline Nb-doped TiO₂ powder materials.

	Unit cell volume / Å ³			
	0 at% Nb	2 at% Nb	5 at% Nb	10 at% Nb
Own data	136.59	136.62	136.94	137.53
<i>Chem. Mater.</i> 2004 , <i>16</i> , 862-871.	136.2	136.4	136.6	137.4
<i>J. Am. Chem. Soc.</i> 2014 , <i>136</i> , 419–426.	136.5	137.1	137.9	138.8
<i>Adv. Funct. Mater.</i> 2014 , <i>24</i> , 5075–5085.	138.9		140.0	141.7
<i>J. Mater. Chem. A</i> 2015 , <i>3</i> , 22969–22974.	136.23	136.52	136.75	-

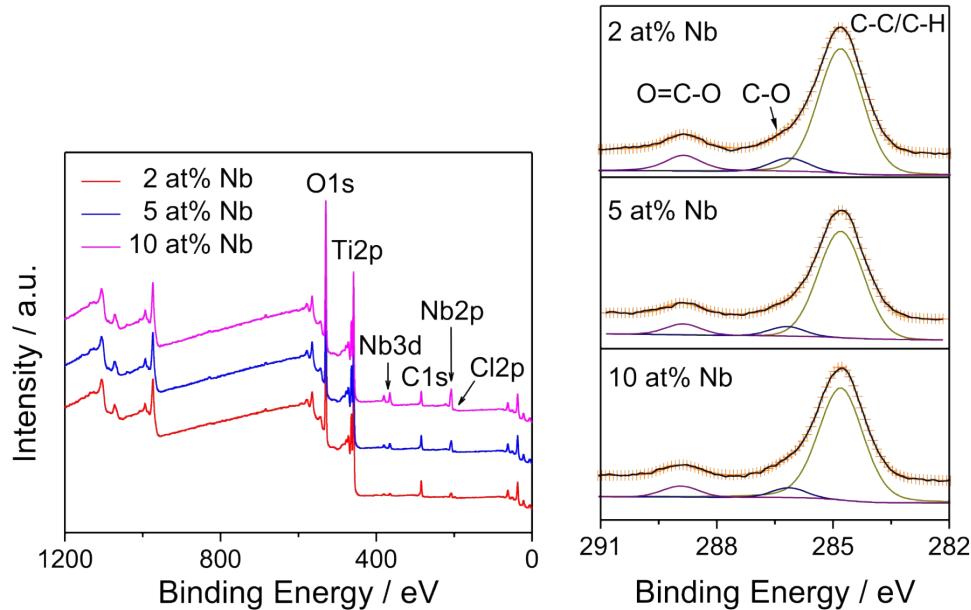


Figure S4. XPS survey spectra (left) and C 1s core level spectra (right) of as-prepared Nb-doped TiO₂ powder samples.

Table S3. XPS peak analysis data.

	Ti 2p _{3/2} / eV			Nb 3d _{5/2} / eV		
	2 at% Nb	5 at% Nb	10 at% Nb	2 at% Nb	5 at% Nb	10 at% Nb
Own data	458.8	458.7	Reduced Ti	207.4	207.4	Reduced Nb
<i>Appl. Phys. Express</i> 2008 , <i>1</i> , 111203.	-	458.7	yes	-	207.5	yes
<i>Adv. Mater.</i> 2009 , <i>21</i> , 2282–2287.	-	459.3	no	-	207.7	no
<i>Adv. Funct. Mater.</i> 2014 , <i>24</i> , 5075–5085.	458.5	458.3	yes	-	206.8	no
<i>J. Mater. Chem. A</i> 2015 , <i>3</i> , 22969–22974.	-	458.2	no	-	206.6	no

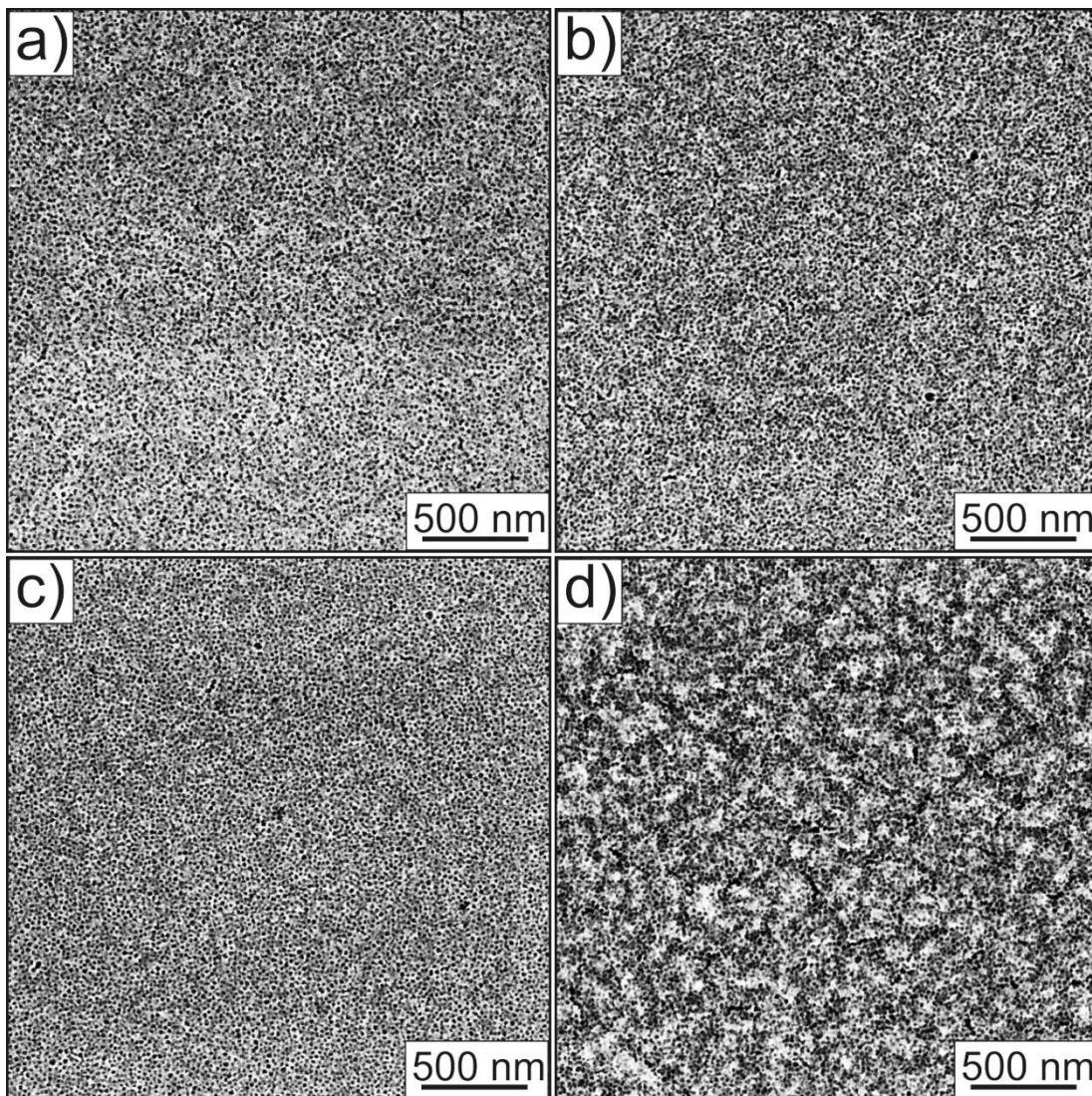


Figure S5. Top-view SEM images of mesoporous Nb-doped TiO₂ thin films. (a) pure TiO₂. (b) 2 at% Nb, (c) 5 at% Nb and (d) 10 at% Nb.

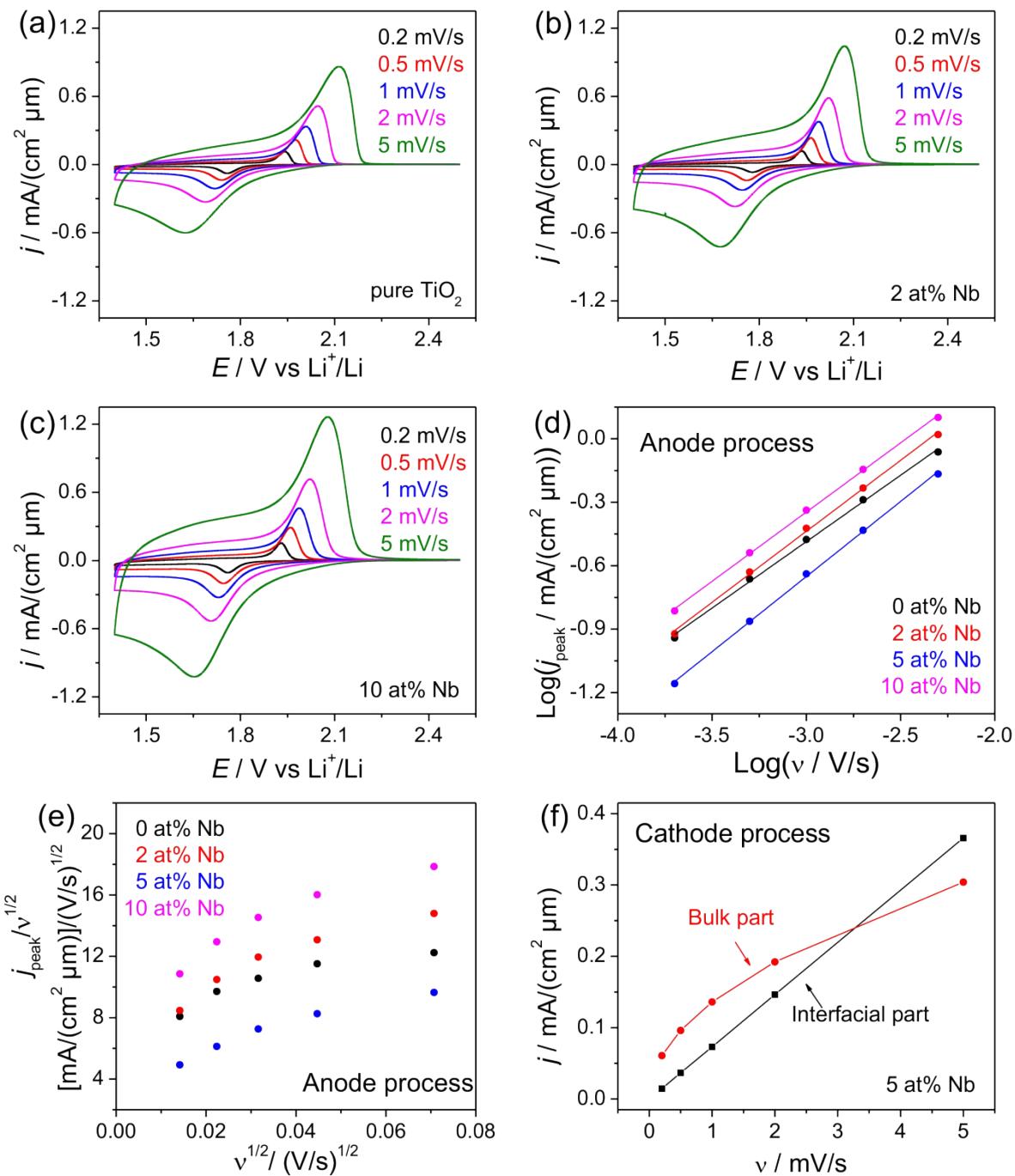


Figure S6. Cyclic Voltammetry data of mesoporous Nb-doped TiO_2 films with different doping level in 1 M LiClO_4 in propylene carbonate. (a) pure TiO_2 , (b) 2 at% Nb and (c) 10 at% Nb. (d) Plot of $\log j_{\text{peak}}$ vs. $\log v$. (e) Plot of $j_{\text{peak}} / v^{1/2}$ vs. $v^{1/2}$. (f) Currents from the bulk and interfacial part at different scanning rates.

Table S4. Effect of doping level (or rather conductivity) on parameter b (Eq. 3), k_F (Eq. 5), pseudocapacitive contribution, chemical diffusion coefficient of Li (anode process) obtained by using a scanning rate of 1 mV/s.

	$\sigma / \text{S cm}^{-1}$	b value	k_F value	Pseudocapacity	$D_{\text{Li}} / \text{cm}^2 \text{ s}^{-1}$
TiO ₂	1×10^{-5}	0.63	7.94	21%	6.3×10^{-16}
2 at% Nb	7.8×10^{-5}	0.67	7.91	30%	6.2×10^{-16}
5 at% Nb	9.8×10^{-5}	0.71	4.28	40%	1.8×10^{-16}
10 at% Nb	7.9×10^{-5}	0.65	10.13	27%	1.0×10^{-15}

Table S5. Overview of used mesoporous films for electrochemical measurements. Surface area was obtained by N₂ physisorption as shown in Fig. 7.

	Film area / cm ²	Thickness / μm	Surface area / cm ²
TiO ₂	4.0	0.36	419
2 at% Nb	3.5	0.16	163
5 at% Nb	4.0	0.16	186
10 at% Nb	4.0	0.15	175

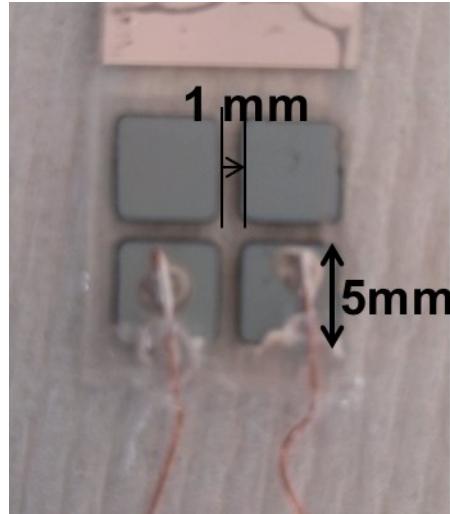


Figure S7. Photograph of conductivity measurement setup.